

Review Article

Design and Simulation of a Broadband Plasmonic Optical Isolator

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In this paper, a new approach for optical isolator based on the Plasmonic effect is proposed. Metallic nanoparticles of different sizes are used to realize the proposed idea. Metallic nanoparticles spin-coated on alumina thin layer that is coated on Silicon waveguide. We demonstrated that the proposed idea operates in a broadband spectral range (more than 800nm) as well as back-propagating wave attenuated more than 120dB. The proposed idea can enhance the isolation ratio and also can provide wider bandwidth for isolation. The proposed idea is based on solution process nanotechnology that is simple, low cost, and available.

Keywords: Optical isolator; Broadband isolation; Nanoparticles; Fe Nanoparticles; Isolation ratio**Introduction**

An optical isolator or optical diode is a device that restricts light to travel in one direction and allows it to go in another direction. An optical isolator is an essential device in optical communication systems and lasers. It prevents back reflections of light, which could damage other devices. A variety of optical isolators have been proposed over the past years. Rayleigh proposed the first optical isolator which was designed utilizing a Faraday rotator and two polarizers. The origin of non-reciprocity was the Faraday rotator. Because of its magnetically induced anisotropy, the light traveling in two directions along the device rotates differently. By using the polarizers, the light gets blocked in one direction. Rayleigh's isolator had some major problems. It could not function as a broadband isolator because the rotator depends on wavelength. The second problem is the strong magnetic field, which was used to induce anisotropy to the rotator. Also, it is challenging to make magnets in smaller sizes, which means this device is bulky and could not be integrated with other devices. Additionally, the magnetic field and Verdet constant are temperature-dependent which makes designing this isolator difficult. Strong dependency on the length of the rotator is another difficulty of this isolator. Some of these issues are remained as a problem for fabrication and developing optical isolators. The primary parameters of an optical isolator are isolation ratio, insertion loss, and bandwidth. To gain a high isolation ratio, low insertion loss, and broad bandwidth several works have been done. In most of the structures, iron or garnet was used as the main material and the anisotropy was induced to the iron or garnet by a magnetic field. Table 1 shows the main parameters of the proposed structures. Broad bandwidth and high isolation have not been reached in the presented works and a broadband isolator with high isolation is strongly needed.

Some of the new designs are discussed in the following. One of the approaches is using chiral plasmonic-metamaterials. It proposes an achromatic optical isolator. It is based on circular dichroism in metamaterials of twisted chains, which is made of metallic Nanoparticles. Broad bandwidth (approximately 300nm) has been

achieved, but the design has a low isolation ratio (less than 5dB). The insertion loss of the proposed isolator is acceptable (nearly 3dB) [39]. Another method is based on a ring resonator. The device consists of a magneto-optical ring resonator with a silver disk embedded in its center. The isolation ratio is reported to reach 20.1dB, and the insertion loss is 0.89dB at the wavelength of 1.38 μ m. The operating bandwidth of the mentioned design is about 10nm, which means it cannot act as a broadband isolator [40]. One of the designs which are compatible with CMOS technology is based on tandem ring modulators. In this scheme, a p-n ring modulator was adopted to reach the isolation function. The maximum isolation ratio of 50dB and insertion loss of 3dB was acquired. The bandwidth of the device is 1.87GHz, which implies it cannot be used as a broadband isolator [41]. One of the trials was based on a magneto-optic Mach-Zehnder interferometer. The design consists of an asymmetric Mach-Zehnder interferometer with a phase shifter. The phase shifter in one of the waveguides is non-reciprocal and is magnetized transversely. In the other waveguide, the phase shifter is reciprocal. Isolation ratio and insertion loss are obtained 50dB and 1dB respectively. The proposed design couldn't function as a broadband device [42]. One of the structures is based on plasmonic. The design is a multi-layer structure of Si, Al₂O₃, and Fe. Fe is used as the magneto-optic material to gain non-reciprocal loss. Si is used as a dielectric of the plasmonic structure. And Al₂O₃ is used to have free carriers and adjust the effective refractive index of the waveguide. High isolation has been attained (800dB/mm) which is acceptable. Because of the high extinction factor of Fe, using it as the metal of the plasmonic structure increase the insertion loss. But it could be compensated by an optical amplifier. Besides, the design could only perform narrowband isolation [43]. In this paper, we demonstrated an isolator with high isolation and ultra-broad bandwidth with a wide incident angle. For the best of the author's knowledge, it has the broadest bandwidth with the highest isolation ratio and widest incident angle among the reported structures.

Design and Simulation

In this section mathematical modeling and physical description

of operation is presented. Figure 1 shows a schematic of the proposed optical isolator.

Figure 1 shows the schematics of our proposed design. It consists of 300nm of Si as substrate, 20nm of Al_2O_3 , and 3000nm of Fe Nanoparticles surrounded by Si. The Nanoparticles have various diameters varying from 160nm to 360nm. Refractive indexes of dielectrics are wavelength-independent. It is determined as 3.5 for Si and 1.74 for Al_2O_3 at the wavelengths 1200-2000 nm. Permittivity tensor of Fe is described as:

$$\epsilon_{je} = \begin{pmatrix} \epsilon_d & -i\gamma & 0 \\ i\gamma & \epsilon_d & 0 \\ 0 & 0 & \epsilon_d \end{pmatrix}$$

where diagonal elements are the permittivity of Fe without magnetization. Its value for different wavelengths is obtained from the data reported by Ordal (1985). The off-diagonal elements are responsible for the anisotropic feature of Fe which is generated using a magnetic field. It is assumed to equal 36.4 in this paper. $i\gamma$ is defined as purely real (it doesn't have an imaginary part), even though having a small imaginary part won't have any major effect on the result. The simulations are performed by the finite element method. The transmittance of the design is shown in Figure 2. As shown there is a

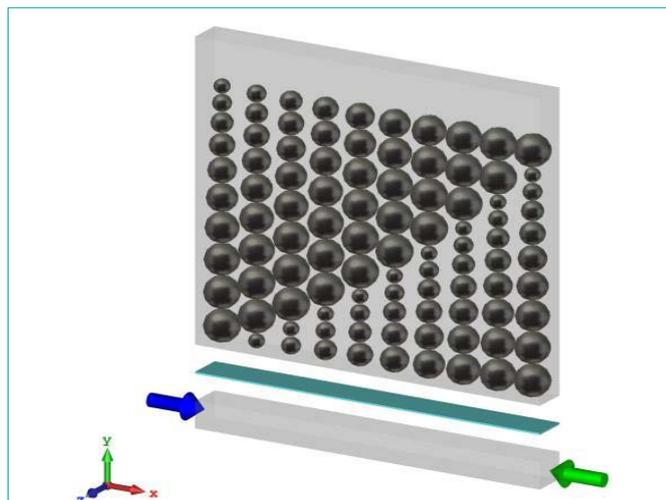


Figure 1: Schematics of the proposed design. From the bottom: 300nm of Si, 20nm of Al_2O_3 , and Fe Nanoparticles surrounded by Si. For the forward direction, port 1 is excited and for the backward direction, port2 is excited.

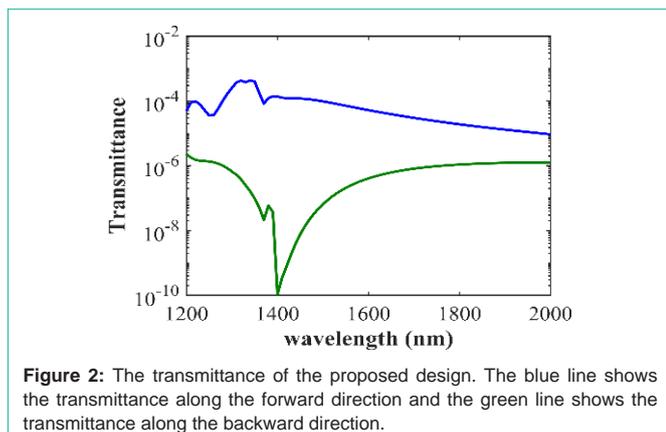


Figure 2: The transmittance of the proposed design. The blue line shows the transmittance along the forward direction and the green line shows the transmittance along the backward direction.

great difference between transmission in the forward and backward direction meaning that the device is an isolator.

Figure 3a shows the Isolation ratio for this design. The isolation ratio is one of the major parameters to evaluate an isolator. Isolation ratio is defined as a ratio of the transmittance in the forward direction to the transmittance in the backward direction:

Table 1: Comparison of different methods for the realization of optical isolators.

Structure	Isolation ratio (dB)	Insertion loss (dB)	Bandwidth (nm)
Non-reciprocal coupling [1]	30	3	Single freq.
Liquid Crystal [2]	30	1	Single freq.
Tandem phase modulator [3]	11	2.3	Single freq.
Guided resonance [4]	25	0	Single freq.
Non-reciprocal optical resonators [5]	19.5	18.8	Single freq.
Photonic crystal heterojunctions [6]	22	12~32	180nm
Ring isolator on SOI [7]	20~80	-	Single freq.
Non-reciprocal Microring resonator [8]	20	-	Single freq.
Ce:YIG/SOI [9]	25	14	Single freq.
Atomic vapor in the hyperfine [10]	30	0.05	Single freq.
MZI [11]	18	-	-
Stimulated Brillouin scattering [12]	20	-	25
All-silicon [13]	28	-	Single freq.
Compact MZI [14]	11	-	Single freq.
Linear and passive [15]	6	-	50
Surface Plasmons [16]	~800	-	Single freq.
Faraday rotator [17]	10~40	-	50
CdSe Quantum Dots [18]	14	-	Single freq.
Ce:YIG on SOI [19]	32	-	Single freq.
Modulation [20]	3~5	-	40
Coupled micro resonators [21]	8	0	Single freq.
Nanorings [22]	35	0	Single freq.
Cryogenic Faraday Isolator [23]	30	-	Single freq.
Mode Conversion [24]	6	8	-
Deposition of Ce:YIG [25]	13	7.4	Single freq.
Grating coupler [26]	20	5.7	14
Micro ring [27]	32	~25	Single freq.
Nonlinear PT-symmetric lattice [28]	68.6	-3.7	Single freq.
Four-wave-mixing	11.3	19	2.5
Canceling phase deviation in MZI [29]	20	35	8
Four-wave-mixing [30]	15	4	Single freq.
Microtoroid optomechanical resonator [31]	10	~15	Single freq.
Active microrcavity [32]	16.5	1.25	Single freq.
Tapered metallic grating [33]	9	0.5	~250
Microcavity [34]	6.5~26	-	Single freq.
Four-wave-mixing [35]	18.3	7	2
Electro-optical emulation [36]	18.5	60	Single freq.
Microresonator [37]	78.6	1	Single freq.
Mimicking nonlinear anti-adiabatic [38]	10	0	~300 (100 THz)

$$Isolation = \frac{T_{forward}}{T_{backward}}$$

An optical isolator is as functioning as its great isolation ratio. The isolation ratio of our design reaches its maximum value at the wavelength of 1400nm with a value of 120dB (33333dB/mm) and its minimum value is 20dB (5555dB/mm) for the wavelength of 2000nm. As discussed before, the generated anisotropy is assumed to compensate for the loss of wave in one direction and its value is equal to the imaginary part of permittivity which is responsible for the loss. If the generated anisotropy is different than the assumed value, the maximum isolation will occur in other wavelengths. The performance of the isolator won't be affected, nonetheless, the value of isolation ratio and insertion loss would change a bit. The figure of merit for optical isolator could be defined as the ratio of optical isolation to average loss:

$$FoM = \frac{loss_{forward} - loss_{backward}}{(loss_{forward} + loss_{backward}) / 2}$$

If an ideal isolator is supposed, the loss mechanism in the forward direction will be zero, and loss in the backward direction would be infinite. Hence the value of FoM for the ideal isolator is -2. Figure 3b shows the figure of merit for the isolator discussed in this paper. For a considerably large range of the bandwidth, the value of FoM equals -2 which this part includes 1310nm and 1550nm wavelengths. For higher isolations, two or more periods of this structure could be used. Simulation shows that isolation of a structure with two periods is twice as high as isolation of one period. In this case, FoM is closer to its ideal form, and the range in which FoM equals -2 is larger than it is in one period.

In addition to the isolation ratio and figure of merit, the propagating wave should have a proper shape across the device. Figure 4a and 4b) shows the magnetic field along the Z direction for $\lambda=1310\text{nm}$ and 1550nm which are standard wavelengths for optical communications. As shown, in both wavelengths Hz in the forward

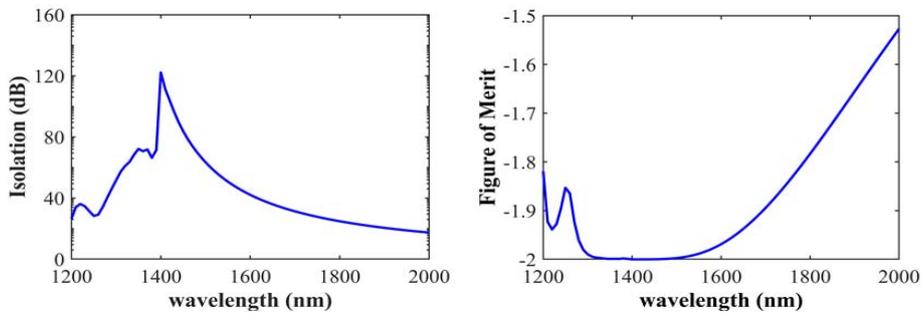


Figure 3: a) Isolation ratio of the plasmonic isolator utilizing Nanoparticles. b) Figure of merit of the proposed design.

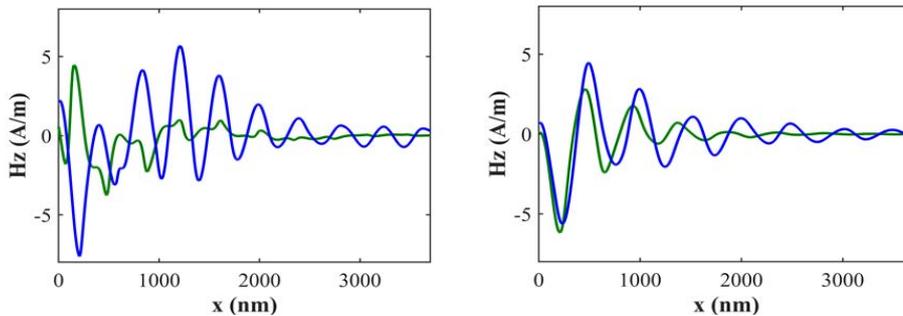


Figure 4: The magnetic field along Z direction a) $\lambda=1310\text{nm}$. b) $\lambda=1550$. The blue line shows Hz in the forward direction and the green line shows Hz in the backward direction.

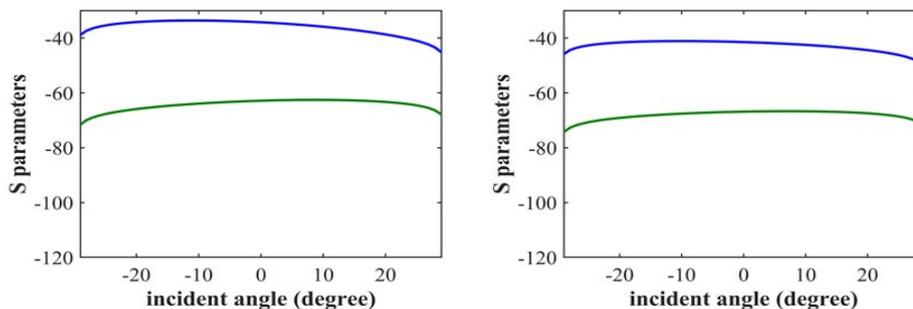


Figure 5: S parameters for different incident angles. a) $\lambda=1310\text{nm}$, b) $\lambda=1550\text{nm}$. The blue line is S21 and the green line is S12.

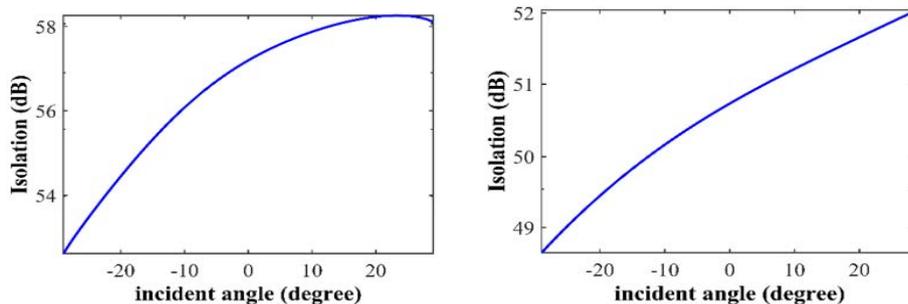


Figure 6: Isolation ratio for different incident angles. a) $\lambda=1310\text{nm}$. b) $\lambda=1550\text{nm}$.

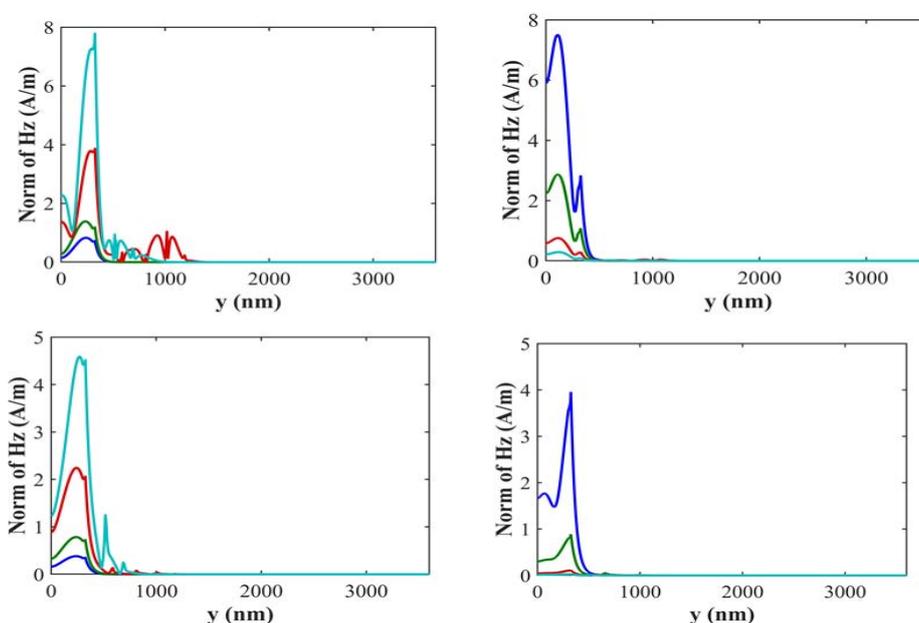


Figure 7: Modes of light along the waveguide. a) $\lambda=1310\text{nm}$ in forward direction. b) $\lambda=1310\text{nm}$ in backward direction. c) $\lambda=1550\text{nm}$ in the forward direction. d) $\lambda=1550\text{nm}$ in backward direction. The cyanide, red, green, and blue lines are for $x=555\text{nm}$, 1295nm , 2405nm , and 3145nm respectively.

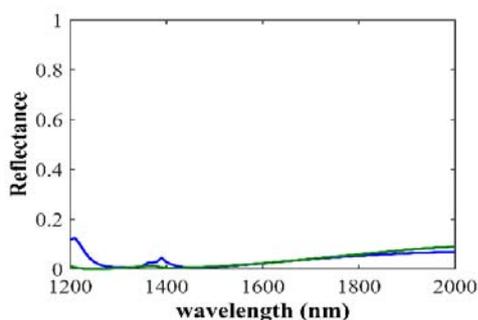


Figure 8: Reflectance for different Wavelengths.

direction has a proper shape.

One of the problems is due to the small size of the isolator, it is hard to excite a port with a specific or with a narrow range of incident angles. This problem is reported in some of the works with an incident angle range as narrow as 0.1 degrees [44]. Figure 5 shows S parameters and Figure 6 shows the isolation ratio for different incident angles. It

is clear from these figures that for a wide range, the incident angle won't affect the performance of the isolator a lot.

For any optical device, it is essential to prove that light is coupled in the waveguide. Mode analysis is commonly used to show this feature. Figure 7 shows modes for 2 important wavelengths of 1310nm and 1550nm. Four cut lines are defined to show the light is coupled properly along the waveguide. The spike shown in the figures is the boundary between Al_2O_3 and Fe Nanoparticles which is the plasmonic waveguide.

As discussed before, the major use of isolators is to prevent unwanted reflection of light, so isolators need to have a small value of reflection. Figure 8 shows the value of reflectance for different wavelengths. Reflectance is nearly zero for all of the bandwidth range. Figure 9 shows reflectance for different incident angles which prove reflectance is nearly zero for a large range of incident angles.

Conclusion

A broadband isolator with high isolation ratio and a wide incident angle is proposed and simulated. It is based on a Plasmonic waveguide

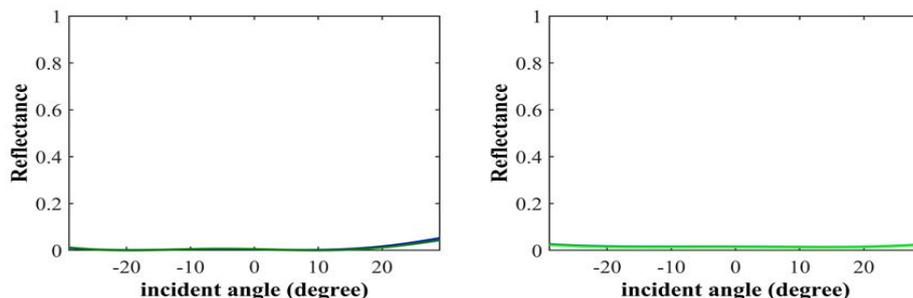


Figure 9: Reflectance for different incident angles. a) $\lambda=1310\text{nm}$. b) $\lambda=1550\text{nm}$. The blue line indicates forward direction and the green line indicates backward direction.

with induced anisotropy. The structure consists of 3 layers Si, Al_2O_3 , and Nanoparticles. The Nanoparticles have different diameters and are made of Fe. The bandwidth of 800nm and maximum isolation of 120dB is gained. For higher isolations, two or more periods of the structure could be used in cascade. It is shown by simulation that in this case, total isolation would be multiplied. For further researches, it is suggested to use other MO substances instead of Fe. Some of these substances have lesser extinction factors than Fe. So replacing Fe with these matters may decrease insertion loss. Thus it would increase the performance of the device. Another approach could be using other ways to obtain non-reciprocity such as non-linear waveguides or materials with constant magnetization. An increasing number of Nanoparticles may have wider bandwidth and choosing the proper radius may adjust the range of the bandwidth to specific applications.

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